

			N19-00141
TED (15) – 2041		Reg. No.	
(REVISION — 2015)		Signature	

DIPLOMA EXAMINATION IN ENGINEERING/TECHNOLOGY/ MANAGEMENT/COMMERCIAL PRACTICE — OCTOBER, 2019

BASIC ELECTRONICS

[Time: 3 hours

(Maximum marks: 100)

PART — A

(Maximum marks: 10)

Marks

- I Answer all questions in one or two sentences. Each question carries 2 marks.
 - 1. Write any two specifications of a resistor.
 - 2. Sketch the V-I characteristics of zener diode.
 - 3. State the importance of peak inverse voltage.
 - 4. Write the significance of the arrow head in the symbol of a transistor.
 - 5. List the uses of capacitors.

 $(5 \times 2 = 10)$

PART — B

(Maximum marks: 30)

- II Answer any five of the following questions. Each question carries 6 marks.
 - 1. Describe the charging and discharging of capacitor.
 - 2. Define drift and diffusion current.
 - 3. With suitable diagram explain the working of a half wave rectifier.
 - 4. Explain with diagram the constructional details of a PNP transistor.
 - 5. Draw the symbol and explain the working of a varactor diode.
 - 6. Define the terms rectification efficiency and ripple factor.
 - 7. Draw the output characteristics of CE configuration and mark the three regions of operation.

 $(5 \times 6 = 30)$



2

Marks

PART — C

(Maximum marks: 60)

(Answer one full question from each unit. Each full question carries 15 marks.)

		Unit — I	
III	(a)	Explain the colour coding of resistors with example and figure.	8
	(b)	With diagram explain the working principle of transformer.	. 7
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IV	(a)	Define self inductance and mutual inductance.	8
	(b)	Derive the effective capacitance of series and parallel combination of capacitors.	7
		Unit — II	
V	(a)	Explain with diagram the formation of PN junction and depletion region.	9
	(b)	Describe zener and avalanche break down.	6
		OR	
VI	(a)	Define doping. Explain the formation of N-type semiconductor.	8
	(b)	Sketch and explain the V-I characteristics of diode.	7
		Unit — III	
VII	(a)	With circuit diagram and waveform explain the working of full wave bridge rectifier.	10
	(b)	Explain the working of negative clamper.	5
•	•	OR	
VIII	(a)	Explain the working of full wave voltage doubler.	8
	(b)	Explain the working of shunt capacitor filter.	7
		Unit — IV	•
IX	(a)	State the effect of temperature in leakage current of transistor.	6
	(b)	Explain the working principle of NPN transistor with suitable diagram.	9
		Or	
X	(a)	Derive the relation between α , β and γ .	6
	(b)	Draw the circuit diagram, input and output characteristics of transistor in CB configuration.	9